



T1635-600G T1650-600G

HIGH PERFORMANCE TRIAC

FEATURES

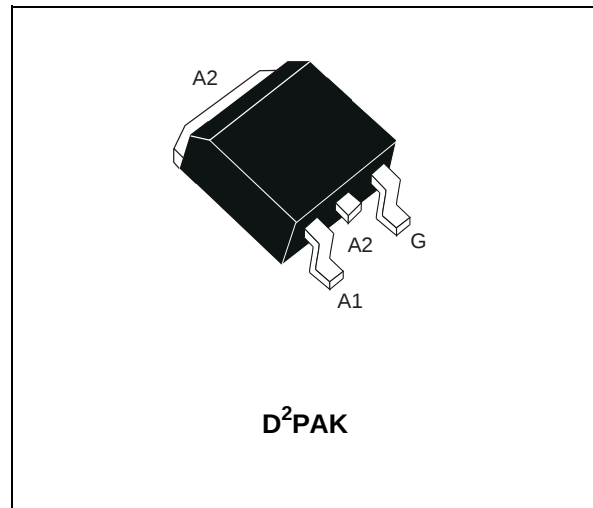
- HIGH COMMUTATION PERFORMANCES
- SNUBBERLESSTM TECHNOLOGY
- HIGH NOISE IMMUNITY (dV/dt)
- HIGH I_{TSM}

DESCRIPTION

The T1635-600G and T1650-600G triacs are using high performance SNUBBERLESS technology.

They are intended for AC control applications using surface mount technology.

These devices are perfectly suited where high commutation and surge performances are required.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{DRM} V_{RRM}	Repetitive peak off-state voltage	$T_j = 125^{\circ}\text{C}$	600	V
$I_{T(RMS)}$	RMS on-state current (360° conduction angle)	$T_c = 105^{\circ}\text{C}$	16	A
I_{TSM}	Non repetitive surge peak on-state current (T_j initial = 25°C)	$t_p = 8.3\text{ms}$	170	A
		$t_p = 10\text{ ms}$	160	
I^2t	I^2t Value for fusing	$t_p = 10\text{ ms}$	128	A^2s
dI/dt	Critical rate of rise of on-state current $I_G = 500\text{ mA}$ $dI_G/dt = 1\text{ A}/\mu\text{s}$.	Repetitive $F = 50\text{ Hz}$	20	$\text{A}/\mu\text{s}$
		Non Repetitive	100	
T_{stg} T_j	Storage temperature range Operating junction temperature range		- 40, + 150 - 40, + 125	$^{\circ}\text{C}$
T	Maximum temperature for soldering during 10s		260	$^{\circ}\text{C}$

T1635-600G / T1650-600G**THERMAL RESISTANCES**

Symbol	Parameter	Value	Unit
Rth(j-a)	Junction to ambient (S=1cm ²)	45	°C/W
Rth(j-c)	Junction to case for DC	1.6	°C/W
Rth(j-c)	Junction to case for AC 360° conduction angle (F=50Hz)	1.2	°C/W

GATE CHARACTERISTICS (maximum values)

$P_G (AV) = 1\text{ W}$ $P_{GM} = 10\text{ W}$ ($t_p = 20\text{ }\mu\text{s}$) $I_{GM} = 4\text{ A}$ ($t_p = 20\text{ }\mu\text{s}$)

ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions		Quadrant		T1635	T1650	Unit
I_{GT}	$V_D = 12\text{ V (DC)}$ $R_L = 33\Omega$	$T_j = 25^\circ\text{C}$	I-II-III	MIN	2		mA
				MAX	35	50	
V_{GT}	$V_D = 12\text{ V (DC)}$ $R_L = 33\Omega$	$T_j = 25^\circ\text{C}$	I-II-III	MAX	1.3		V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3\text{ k}\Omega$	$T_j = 125^\circ\text{C}$	I-II-III	MIN	0.2		V
I_H^*	$I_T = 100\text{ mA}$ Gate open	$T_j = 25^\circ\text{C}$		MAX	35	50	mA
I_L	$I_G = 1.2 I_{GT}$	$T_j = 25^\circ\text{C}$	I-III	MAX	50	60	mA
			II	MAX	80	120	
V_{TM}^*	$I_{TM} = 22.5\text{ A}$ $t_p = 380\mu\text{s}$	$T_j = 25^\circ\text{C}$		MAX	1.5		V
I_{DRM}	$V_D = V_{DRM}$	$T_j = 25^\circ\text{C}$		MAX	5		μA
I_{RRM}	$V_R = V_{RRM}$	$T_j = 125^\circ\text{C}$		MAX	2		mA
dV/dt^*	Linear slope up to $V_D = 67\% V_{DRM}$ Gate open	$T_j = 125^\circ\text{C}$		MIN	500	1000	V/ μs
$(dI/dt)_c^*$	Without snubber	$T_j = 125^\circ\text{C}$		MIN	8.5	14	A/ms

* For either polarity of electrode A2 voltage with reference to electrode A1.

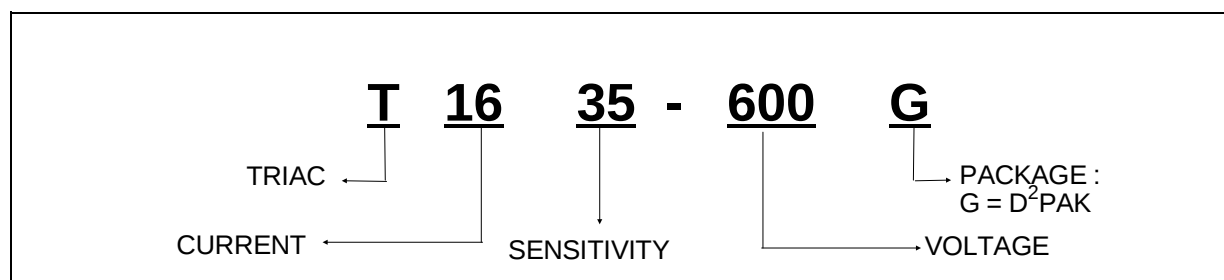
ORDERING INFORMATION Add "-TR" suffix for Tape & Reel shipment

Fig. 1: Maximum power dissipation versus RMS on-state current.

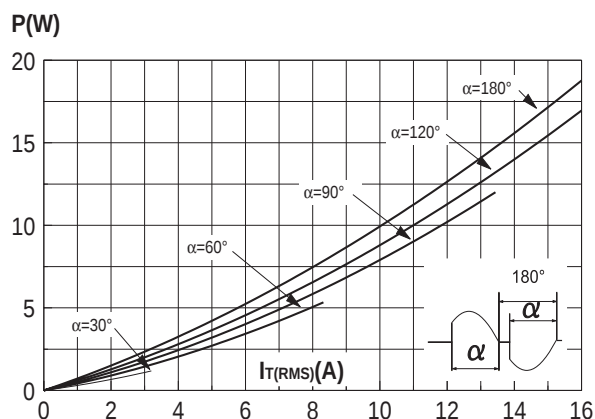


Fig. 2: Correlation between maximum power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink+contact.

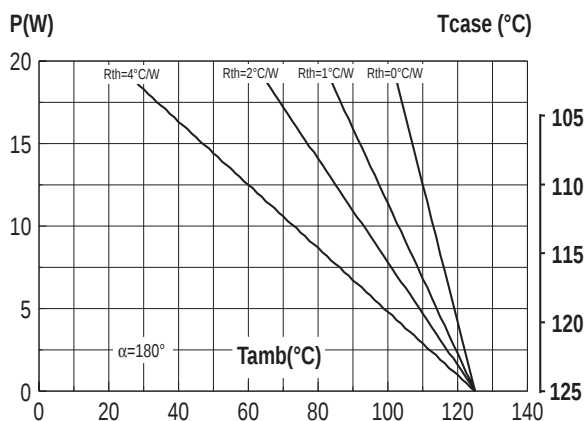


Fig. 3: RMS on-state current versus case temperature.

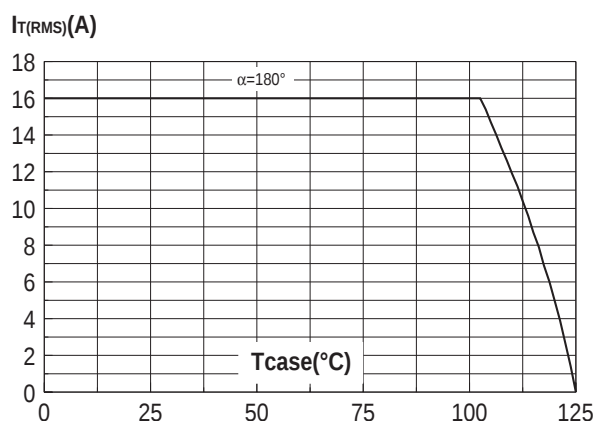


Fig. 4: Relative variation of thermal impedance versus pulse duration.

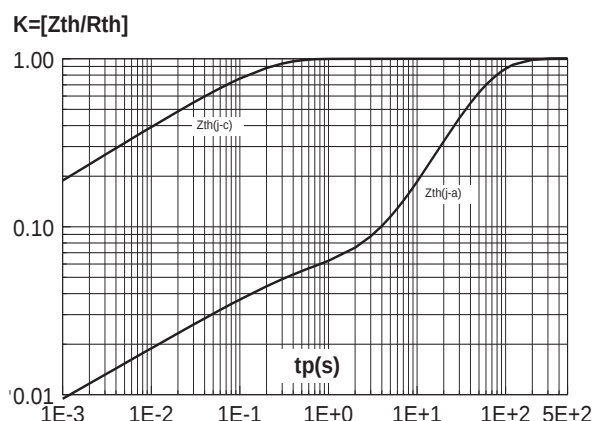


Fig. 5: Relative variation of gate trigger current and holding current versus junction temperature (typical values).

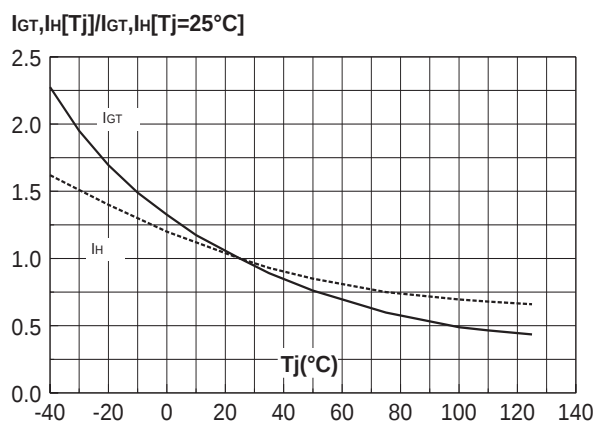


Fig. 6: Non repetitive surge peak on-state current versus number of cycles.

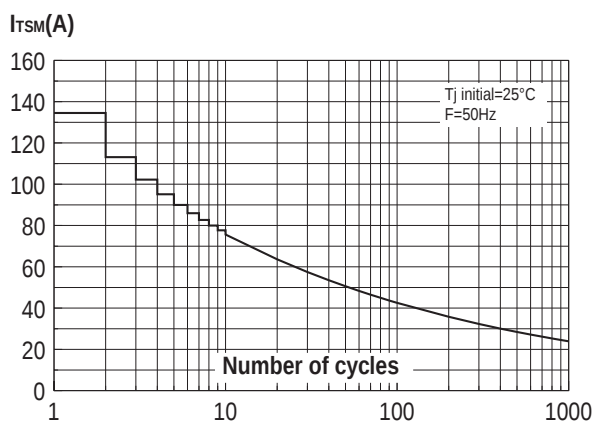


Fig. 7: Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I^2t .

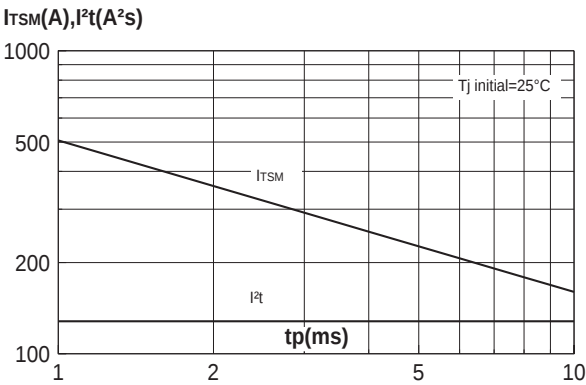


Fig. 9: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: 35 μm).

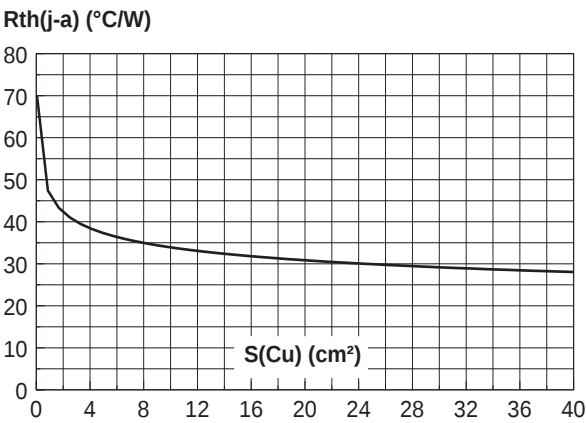


Fig. 8: On-state characteristics (maximum values).

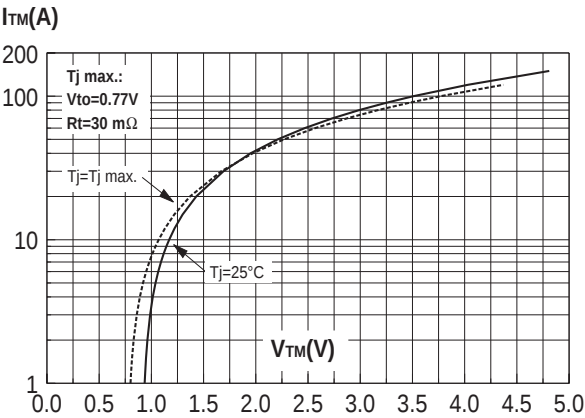
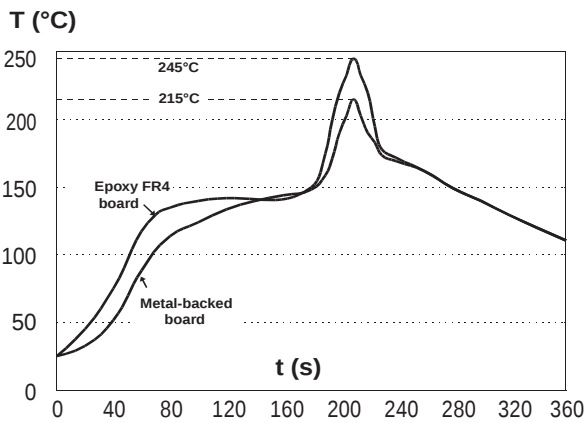
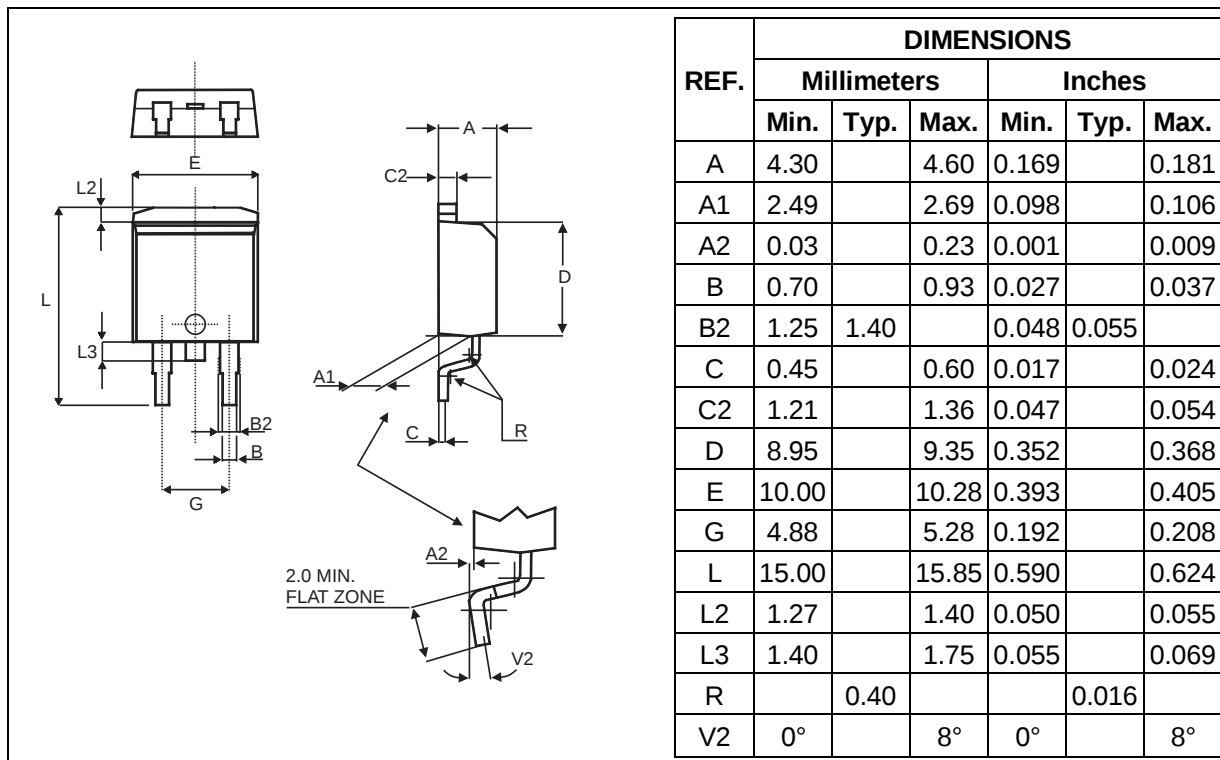
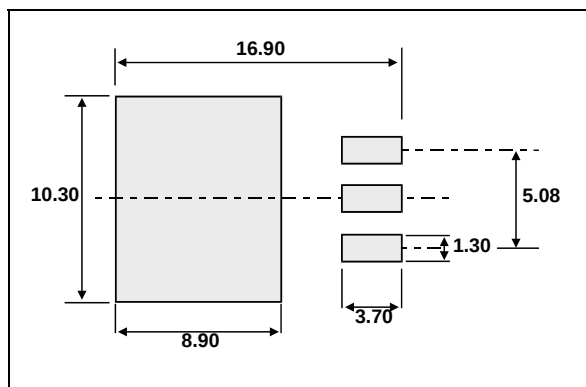


Fig. 10: Typical reflow soldering heat profile, either for mounting on FR4 or metal-backed boards.



PACKAGE MECHANICAL DATA
D²PAK

FOOT PRINT DIMENSIONS (in millimeters)

MARKING

TYPE	MARKING
T1635-600G	T1635 600G
T1650-600G	T1650 600G

PACKING

Tube : 50 units

Tape and reel : 500 units

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